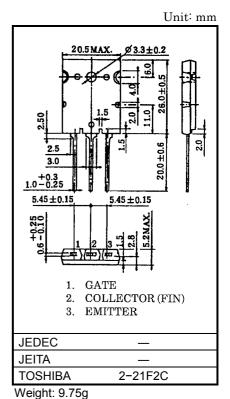
<u>TOSHIBA</u>

TOSHIBA INSULATED GATE BIPOLAR TRANSISTOR SILICON N CHANNEL IGBT

GT50J102

HIGH POWER SWITCHING APPLICATIONS MOTOR CONTROL APPLICATIONS

- The 3rd. Generation.
- Enhancement–Mode.
- High Speed. : $t_f = 0.30 \mu s$ (Max.)
- Low Saturation Voltage. $: V_{CE(sat)} = 2.7V$ (Max.)



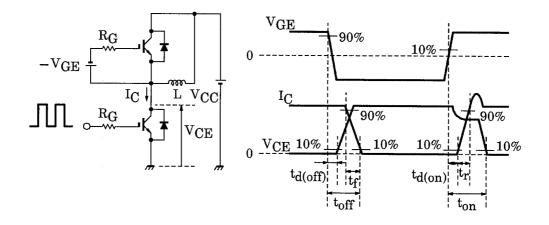
MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT	
Collector-Emitter Voltage		V _{CES}	600	V	
Gate-Emitter Voltage		V _{GES}	±20	V	
Collector Current	DC	Ι _C	50	A	
	1ms	I _{CP}	100		
Collector Power Dissipation		P _C	200	W	
Junction Temperature		Tj	150	°C	
Storage Temperature Range		T _{stg}	-55~150	°C	
Screw Torque		—	0.8	N∙m	

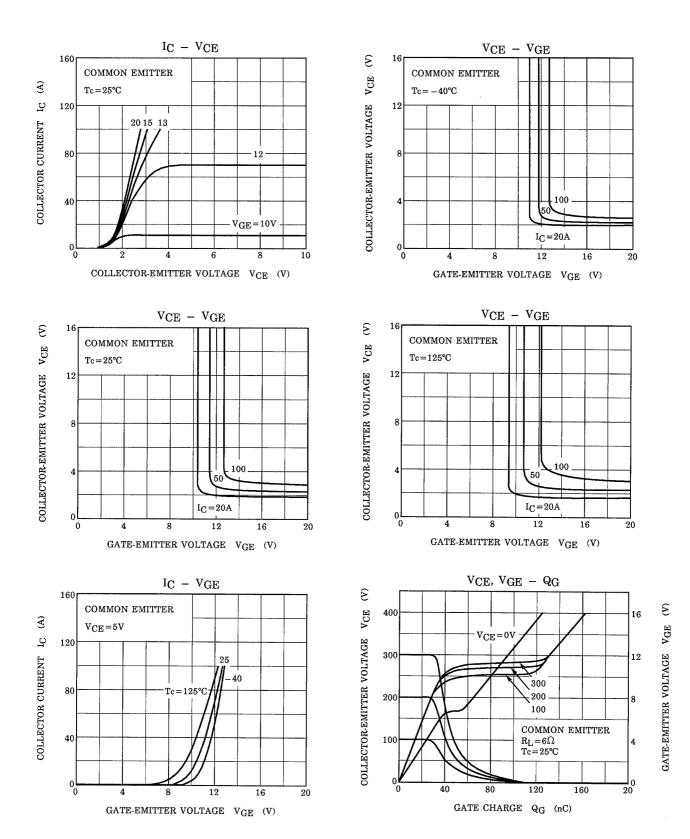
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARA	CTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Gate Leakage Curr	rent	I _{GES}	V _{GE} = ±20V, V _{CE} = 0	—	_	±500	nA
Collector Cut-Off	Current	ICES	V _{CE} = 600V, V _{GE} = 0	_	_	1.0	mA
Gate-Emitter Cut-off Voltage		V _{GE(OFF)}	I _C = 5mA, V _{CE} = 5V	5.0	7.0	8.0	V
Collector-Emitter Saturation Voltage		V _{CE(sat)}	I _C = 50A, V _{GE} = 15V	—	2.1	2.7	V
Input Capacitance		C _{ies}	V _{CE} = 10V, V _{GE} = 0 f = 1MHz	_	4500		pF
Switching Time	Turn-on delayTime	t _{d(on)}		—	0.08		
	Rise Time	tr	Inductive Load	_	0.12	_	
	Turn-on Time	t _{on}	V _{CC} = 300V V _{GE} = ±15V	_	0.40	_	
	Turn-off delay Time	t _{d(off)}	$I_{\rm C} = 50 \text{A}$ $R_{\rm G} = 24 \Omega$	_	0.20	_	μs
	Fall Time	t _f	(Note 1)	_	0.15	0.30	
	Turn-off Time	t _{off}		_	0.50	_	
Thermal Resistance		R _{th(j−c)}		—	_	0.625	V

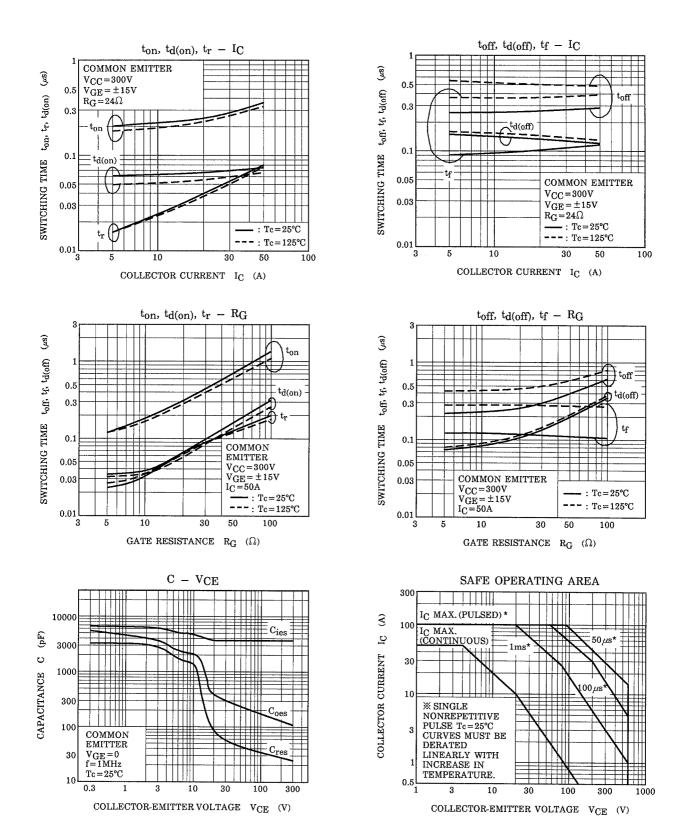
Note 1: Switching. time measurement circuit and input / output waveforms

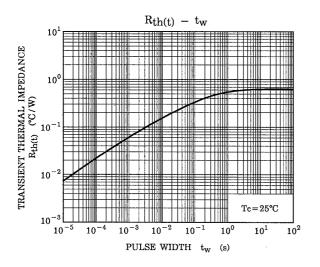


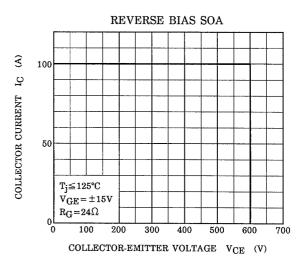
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